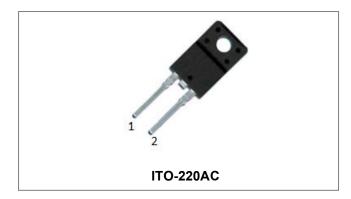






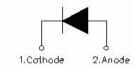
SDURF560A ULTRAFAST RECTIFIER



Applications

- Antiparallel diode for high frequency switching devices
- Anti saturation diode
- Snubber diode
- Free wheeling diode in converters and motor control circuits
- Rectifiers in switch mode power supplies (SMPS)
- · Inductive heating and melting
- Uninterruptible power supplies (UPS)
- Ultrasonic cleaners and welders

Circuit Diagram



Features

- Ultra-Fast switching
- · High current capability
- Low reverse leakage current
- High surge current capability
- This is a Pb free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ V_{R} \end{array}$	-	600	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=100°C, rectangular wave form	5	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3ms, Half Sine pulse	60	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop *	V _{F1}	@5A, Pulse, T _J = 25°C	1.14	1.7	V
Reverse Current *	I _{R1}	@V _R = rated V _R , T _J = 25°C	0.11	5	μA
	I _{R2}	$@V_R = \text{rated } V_R$, $T_J = 125^{\circ}C$	1	500	μΑ
Reverse Recovery Time	t _{rr}	I _F =500mA, I _R =1A,and I _{rm} =250mA	31	35	ns

Pulse width < 300 μs, duty cycle < 2%

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Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case	R _θ JC	DC operation	4.5	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AC			

Ratings and Characteristics Curves

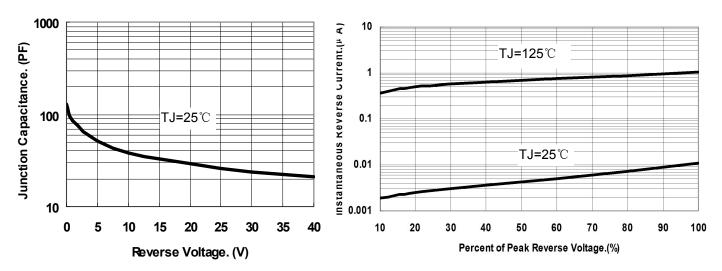


Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics

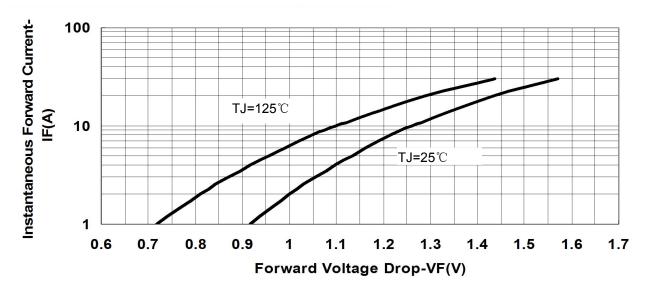


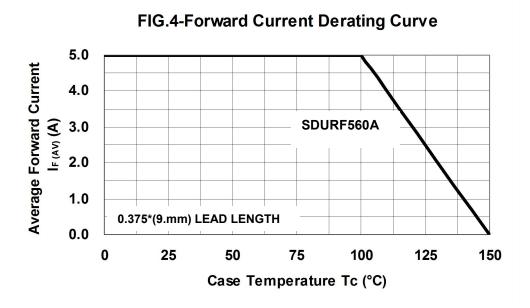
Fig.3-Typical Forward Voltage Drop Characteristics

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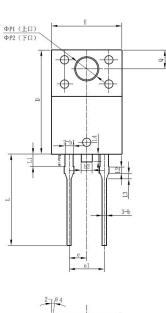


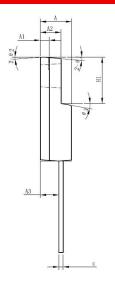






Mechanical Dimensions ITO-220AC







CVMDOL	Millimeters					
SYMBOL	MIN.	TYP.	MAX.			
Α	4.30	4.50	4.70			
A1	1.10	1.30	1.50			
A2	2.80	3.00	3.20			
A3	2.50	2.70	2.90			
b	0.50	0.60	0.75			
b1	1.10	1.20	1.35			
b2	1.50	1.60	1.75			
С	0.55	0.60	0.75			
D	14.80	15.00	15.20			
E	9.96	10.16	10.36			
е	_	2.55	_			
e1	_	5.10	-			
H1	6.50	6.70	6.90			
L	12.70	13.20	13.70			
<u>L1</u>	1.60	1.80	2.00			
L2	0.80	1.00	1.20			
L3	0.60	0.80	1.00			
<u>L4</u>	-	1.10	1.50			
ФР1(上□)	3.30	3.50	3.70			
ΦP2 (下口)	2.99	3.19	3.39			
Q	2.50	2.70	2.90			
Θ1		5°				
Θ2		4°				
Θ3		10°				
Θ4		5°				
Θ5		5°				

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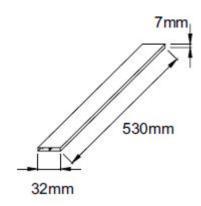








Tube Specification



Marking Diagram



Where XXXXX is YYWWL

 SDUR
 = Device Type

 F
 = Package type

 5
 = Forward Current (5A)

 60
 = Reverse Voltage (600V)

 A
 = A

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

 Cautions:
 Molding resin

 Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping	
SDURF560A	ITO-220AC (Pb-Free)	50 pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.









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